

## NPN Silicon Darlington Transistors

SIEMENS AKTIENGESELLSCHAFT 5C 04395 D

BD 675

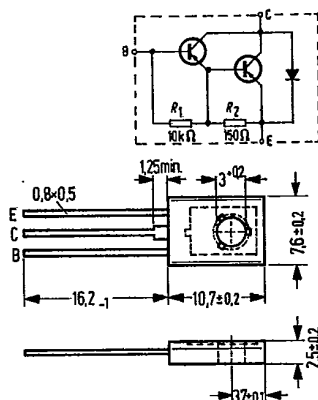
BD 677

BD 679

## Epibase power darlington transistors (40 W)

BD 675, BD 677, and BD 679 are monolithic NPN silicon epibase power darlington transistors with diode and resistors in a TO 126 plastic package (12 A 3 DIN 41869, sheet 4). The collectors of the two transistors are electrically connected to the metallic mounting area. These darlington transistors for AF applications are outstanding for particularly high current gain. Together with BD 676, BD 678, and BD 680 they are especially suitable for complementary AF push-pull output stages and color TV correction stages.

Type	Ordering code
BD 675	Q62702-D238
BD 677	Q62702-D240
BD 679	Q62702-D242
BD 675/BD 676 paired	Q62702-D244
BD 677/BD 678 paired	Q62702-D245
BD 679/BD 680 paired	Q62702-D246
Mica washer	Q62902-B62
Spring washer	Q62902-B63
A 3 DIN 137	



Approx. weight 0.5 g. Dimensions in mm

## Maximum ratings

	BD 675	BD 677	BD 679	
Collector-emitter voltage	$V_{CE0}$ 45	60	80	V
Collector-base voltage	$V_{CBO}$ 45	60	80	V
Base-emitter voltage	$V_{EBO}$ 5	5	5	V
Collector current	$I_C$ 4	4	4	A
Collector-peak current ( $t \leq 1$ ms)	$I_{CM}$ 7	7	7	A
Base current	$I_B$ 0.1	0.1	0.1	A
Storage temperature	$T_{stg}$	-55 to +150		°C
Junction temperature	$T_j$ 150	150	150	°C
Total power dissipation ( $T_{case} \leq 25$ °C; $V_{CE} \leq 20$ V)	$P_{tot}$ 40	40	40	W

## Thermal resistance

Junction to ambient air	$R_{thJA}^{1)}$	<100	<100	<100	K/W
Junction to case	$R_{thJC}$	<3.12	<3.12	<3.12	K/W

1) Transistor fixing with M 3 screw, starting torque  $M_A \leq 0.5$  to 0.8 Nm. If a 50  $\mu$  mica washer (ungreased) is used, the thermal resistance increases by 8 K/W and in case of a greased one by 4 K/W. Below the screw head, a washer or a spring washer should be used.

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Static characteristics ( $T_{amb} = 25^{\circ}\text{C}$ )

		BD 675	BD 677	BD 679	
Collector cutoff current ( $V_{CB} = V_{CBmax}$ )	$I_{CBO}$	<0.2	<0.2	<0.2	mA
( $V_{BC} = V_{CBmax}$ , $T_{amb} = 100^{\circ}\text{C}$ )	$I_{CBO}$	<2	<2	<2	mA
Collector cutoff current ( $V_{CE} = 0.5 V_{CEmax}$ )	$I_{CEO}$	<0.5	<0.5	<0.5	mA
Emitter cutoff current ( $V_{EB} = 5 \text{ V}$ )	$I_{EBO}$	<5	<5	<5	mA
Collector-emitter breakdown voltage ( $I_C = 100 \text{ mA}$ ) <sup>1)</sup>	$V_{(BR)CEO}$	>45	>60	>80	V
Collector-base breakdown voltage ( $I_C = 1 \text{ mA}$ )	$V_{(BR)CBO}$	>45	>60	>80	V
Emitter-base breakdown voltage ( $I_E = 5 \text{ mA}$ )	$V_{(BR)EBO}$	>5	>5	>5	V
Collector emitter saturation voltage ( $I_C = 50 \text{ mA}$ ; $V_{CE} = 3 \text{ V}$ )	$h_{FE}$	750	750	750	—
( $I_C = 1.5 \text{ A}$ ; $V_{CE} = 3 \text{ V}$ )	$h_{FE}$	>750	>750 (3000)	>750 (3000)	—
( $I_C = 4 \text{ A}$ ; $V_{CE} = 3 \text{ V}$ )	$h_{FE}$	1000	1000	1000	—
Base-emitter forward voltage ( $I_C = 1.5 \text{ A}$ ; $V_{CE} = 3 \text{ V}$ )	$V_{BE}$	<2.5	<2.5	<2.5	V
Collector-emitter saturation voltage ( $I_C = 1.5 \text{ A}$ ; $I_B = 30 \text{ mA}$ )	$V_{CEsat}$	<2.5	<2.5	<2.5	V
Forward voltage of the protective diode at $I_F = 3 \text{ A}$	$V_F$	1.8	1.8	1.8	V

Dynamic characteristics ( $T_{amb} = 25^{\circ}\text{C}$ )

Transition frequency ( $I_C = 1.5 \text{ A}$ ; $V_{CE} = 3 \text{ V}$ ; $f = 1 \text{ MHz}$ )	$f_T$	7 (>1)	7 (>1)	7 (>1)	MHz
Cutoff frequency in common emitter configuration ( $I_C = 1.5 \text{ A}$ ; $V_{CE} = 3 \text{ V}$ )	$f_{hfe}$	60	60	60	kHz

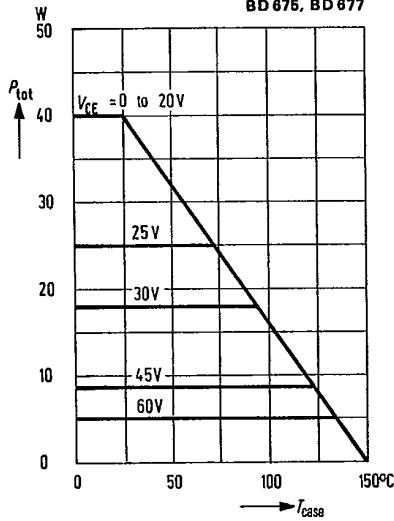
1)  $t = 200 \mu\text{s}$ , duty cycle 1%.

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BD 675  
BD 677  
BD 679

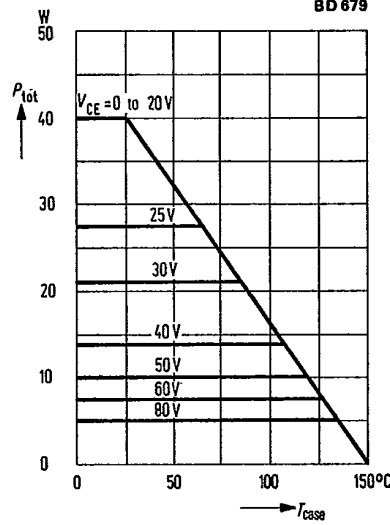
Total perm. power dissipation  
versus temperature  
 $P_{tot} = f(T_{case}); V_{CE} = \text{parameter}$

BD 675, BD 677



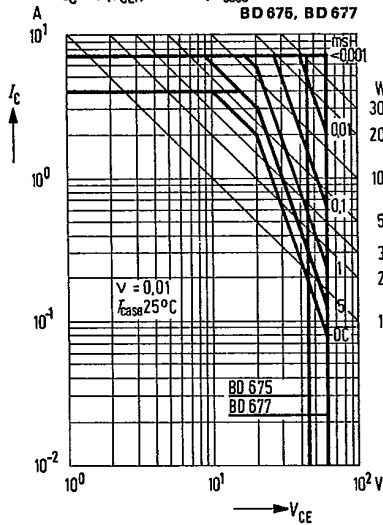
Total perm. power dissipation  
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BD 679



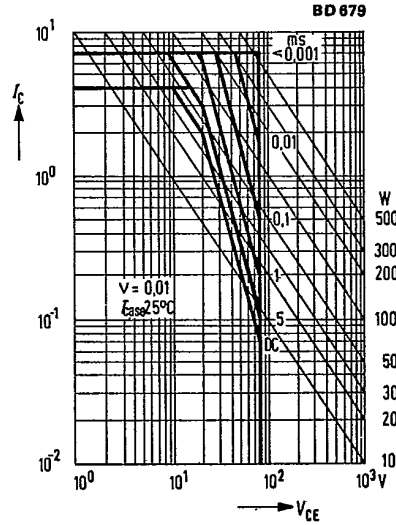
Permissible operating range  
 $I_C = f(V_{CE}); v = 0.01; T_{case} = 25^\circ\text{C}$

BD 675, BD 677



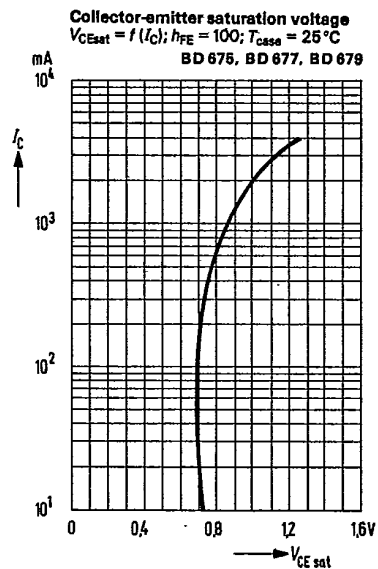
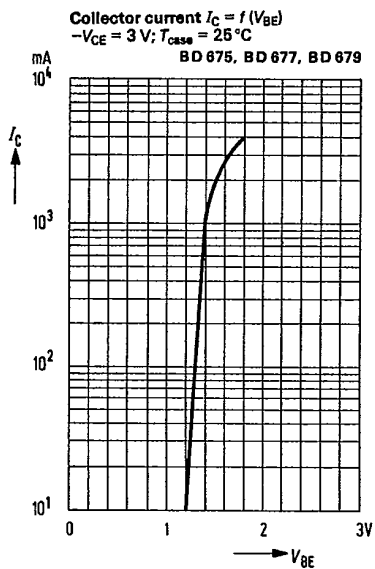
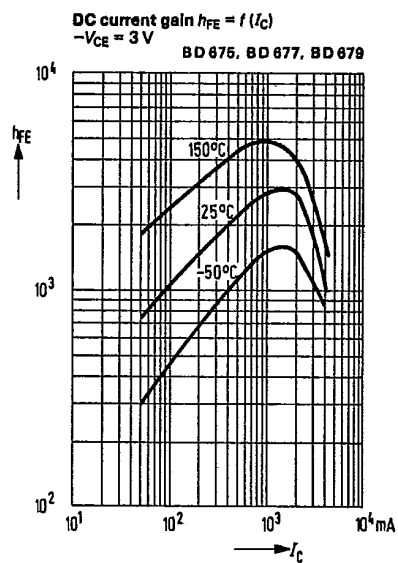
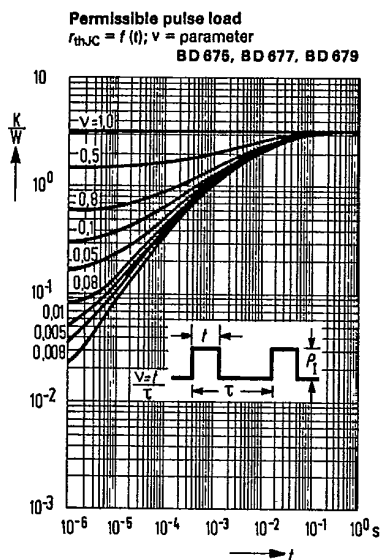
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Datasheets for electronics components.